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1N58 GOLD BONDED GERMANIUM DIODE

FEATURES

Low forward voltage drop—low power consumption
Thirty years of proven reliability—one million hours mean time between failures (MTBF)
Very low noise level
Metallurgically bonded

ABSOLUTE MAXIMUM RATINGS (at 25 °C, unless otherwise specified)

Peak Inverse Voltage

100 Volts

Peak Forward Current

500 mA

Operating Temperature Range

- 65 °C to 85 °C

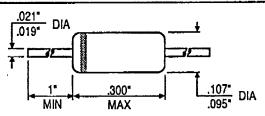
Average Power Dissipation

80 mW

ELECTRICAL CHARACTERISTICS

	Symbol	Conditions	Min	Max	Unit	T °C	
Peak Inverse Voltage	PIV	1 mA	100		V	25 ℃	
Reverse Current	lr .	100 V		800	μΑ	25 °C	
Forward Voltage	Vf	5 mA		1	V	25 °C	
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MECHANICAL



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Quality Semi-Conductors